



Features

- Maximized electromagnetic interference (EMI) suppression using Cypress's Spread Spectrum technology
- Single-chip system frequency synthesizer for Intel[®] 440BX AGPset
- Three copies of CPU output
- · Seven copies of PCI output
- One 48 MHz output for USB/one 24 MHz for SIO
- Two buffered reference outputs
- Two IOAPIC outputs
- 17 SDRAM outputs provide support for four DIMMs
- Supports frequencies up to 150 MHz
- SMBus interface for programming
- · Power management control inputs

Key Specifications

Logic Block Diagram

CPU Cycle-to-Cycle Jitter:	250 ps
CPU to CPU Output Skew:	175 ps
PCI to PCI Output Skew:	500 ps
SDRAMIN to SDRAM0:15 Delay:	3.7 ns typ.
V _{DDQ3} :	3.3V±5%
V _{DDQ2} :	2.5V±5%
SDRAM0:15 (leads) to SDRAM F Skew:	0.4 ns tvp.

Table 1. Mode Input Table

Mode	Pin 3
0	PCI_STOP#
1	REF0

Table 2. Pin Selectable Frequency

	Input A	ddress	3	CPU_F, 1:2	PCI_F, 0:5	
FS3	FS2	FS1	FS0	(MHz)	(MHz)	
1	1	1	1	133.3	33.3 (CPU/4)	
1	1	1	0	124	31 (CPU/4)	
1	1	0	1	150	37.5 (CPU/4)	
1	1	0	0	140	35 (CPU/4)	
1	0	1	1	105	35 (CPU/3)	
1	0	1	0	110	36.7 (CPU/3)	
1	0	0	1	115	38.3 (CPU/3)	
1	0	0	0	120	40 (CPU/3)	
0	1	1	1	100	33.3 (CPU/3)	
0	1	1	0	133.3	44.43 (CPU/3)	
0	1	0	1	112	37.3 (CPU/3)	
0	1	0	0	103	34.3 (CPU/3)	
0	0	1	1	66.8	33.4 (CPU/2)	
0	0	1	0	83.3	41.7 (CPU/2)	
0	0	0	1	75	37.5 (CPU/2)	
0	0	0	0	124	41.3 (CPU/3)	

Pin Configuration^[1]





Pin Definitions

Pin Name	Pin No.	Pin Type	Pin Description		
CPU1:2	51, 49	0	CPU Outputs 1 and 2: Frequency is set by the FS0:3 inputs or through serial input interface, see <i>Table 2</i> and <i>Table 6</i> . These outputs are affected by the CLK_STOP# input.		
CPU_F	52	0	<i>Free-Running CPU Output:</i> Frequency is set by the FS0:3 inputs or through serial input interface, see <i>Table 2</i> and <i>Table 6</i> . This output is not affected by the CLK_STOP# input.		
PCI1:5	11, 12, 13, 14, 16	0	PCI Outputs 1 through 5: Frequency is set by the FS0:3 inputs or through serial input interface, see <i>Table 2</i> and <i>Table 6</i> . These outputs are affected by the PCI_STOP# input.		
PCI0/FS3	9	I/O	PCI Output/Frequency Select Input: As an output, frequency is set by the FS0:3 inputs or through serial input interface, see <i>Table 2</i> and <i>Table 6</i> . This output is affected by the PCI_STOP# input. When an input, latches data selecting the frequency of the CPU and PCI outputs.		
PCI_F/MODE	8	I/O	<i>Free Running PCI Output:</i> Frequency is set by the FS0:3 inputs or through serial input interface, see <i>Table 2</i> and <i>Table 6</i> . This output is not affected by the PCI_STOP# input. When an input, selects function of pin 3 as described in <i>Table 1</i> .		
CLK_STOP#	47	Ι	CLK_STOP# Input: When brought LOW, affected outputs are stopped LOW after completing a full clock cycle (2–3 CPU clock latency). When brought HIGH, affected outputs start beginning with a full clock cycle (2–3 CPU clock latency).		
IOAPIC_F	54	0	<i>Free-running IOAPIC Output:</i> This output is a buffered version of the reference input which is not affected by the CPU_STOP# logic input. Its swing is set by voltage applied to VDDQ2.		
IOAPIC0	55	0	IOAPIC Output: Provides 14.318 MHz fixed frequency. The output voltage swing is set by voltage applied to VDDQ2. This output is disabled when CLK_STOP# is set LOW.		
48MHz/FS1	29	I/O	48 MHz Output: 48 MHz is provided in normal operation. In standard systems, this output can be used as the reference for the Universal Serial Bus. Upon power up, FS1 input will be latched, setting output frequencies as described in <i>Table 2</i> .		
24MHz/FS0	30	I/O	24 MHz Output: 24 MHz is provided in normal operation. In standard systems, this output can be used as the clock input for a Super I/O chip. Upon power up, FS0 input will be latched, setting output frequencies as described in <i>Table 2</i> .		
REF1/FS2	2	I/O	Reference Output: 14.318 MHz is provided in normal operation. Upon power-up, FS2 input will be latched, setting output frequencies as described in <i>Table</i> 2.		
REF0 (PCI_STOP#)	3	I/O	<i>Fixed 14.318 MHz Output 0 or PCI_STOP# Pin:</i> Function determined by MODE pin. The PCI_STOP# input enables the PCI 0:5 outputs when HIGH and causes them to remain at logic 0 when LOW. The PCI_STOP signal is latched on the rising edge of PCI_F. Its effects take place on the next PCI_F clock cycle. As an output, this pin provides a fixed clock signal equal in frequency to the reference signal provided at the X1/X2 pins (14.318 MHz).		
SDRAMIN	17	Ι	Buffered Input Pin: The signal provided to this input pin is buffered to 17 outputs (SDRAM0:15, SDRAM_F).		
SDRAM0:15	44, 43, 41, 40, 39, 38, 36, 35, 22, 21, 19, 18, 33, 32, 25, 24	0	Buffered Outputs: These sixteen dedicated outputs provide copies of the signal provided at the SDRAMIN input. The swing is set by VDDQ3, and they are deactivated when CLK_STOP# input is set LOW.		
SDRAM_F	46	0	<i>Free-Running Buffered Output:</i> This output provides a single copy of the SDRAMIN input. The swing is set by VDDQ3; this signal is unaffected by the CLK_STOP# input.		
SCLK	28	Ι	Clock pin for SMBus circuitry.		
SDATA	27	I/O	Data pin for SMBus circuitry.		
X1	5	I	Crystal Connection or External Reference Frequency Input: This pin has dual functions. It can be used as an external 14.318 MHz crystal connection or as an external reference frequency input.		
X2	6	I	<i>Crystal Connection:</i> An input connection for an external 14.318-MHz crystal. If using an external reference, this pin must be left unconnected.		
VDDQ3	1, 7, 15, 20, 31, 37, 45	Р	Power Connection: Power supply for core logic, PLL circuitry, SDRAM output buffers, PCI output buffers, reference output buffers, and 48 MHz/24 MHz output buffers. Connect to 3.3V.		



Pin Definitions (continued)

Pin Name	Pin No.	Pin Type	Pin Description
VDDQ2	50, 56		Power Connection: Power supply for IOAPIC and CPU output buffers. Connect to 2.5V or 3.3V.
GND	4, 10, 23, 26, 34, 42, 48, 53		Ground Connections: Connect all ground pins to the common system ground plane.

Overview

The CYW150 was designed as a single-chip alternative to the standard two-chip Intel 440BX AGPset clock solution. It provides sufficient outputs to support most single-processor, four SDRAM DIMM designs.

Functional Description

I/O Pin Operation

Pins 2, 8, 9, 29, and 30 are dual-purpose I/O pins. Upon power-up these pins act as logic inputs, allowing the determination of assigned device functions. A short time after power-up, the logic state of each pin is latched and the pins become clock outputs. This feature reduces device pin count by combining clock outputs with input select pins.

An external 10-k Ω "strapping" resistor is connected between the I/O pin and ground or V_{DD}. Connection to ground sets a latch to "0," connection to V_{DD} sets a latch to "1." *Figure 1* and *Figure 2* show two suggested methods for strapping resistor connections.

Upon CYW150 power-up, the first 2 ms of operation are used for input logic selection. During this period, the five I/O pins (2, 8, 9, 29, 30) are three-stated, allowing the output strapping resistor on the I/O pins to pull the pins and their associated capacitive clock load to either a logic HIGH or LOW state. At the end of the 2-ms period, the established logic "0" or "1" condition of the I/O pin is latched. Next the output buffer is enabled, converting the I/O pins into operating clock outputs. The 2-ms timer starts when V_{DD} reaches 2.0V. The input bits can only be reset by turning V_{DD} off and then back on again.

It should be noted that the strapping resistors have no significant effect on clock output signal integrity. The drive impedance of clock output (< 40Ω , nominal) is minimally affected by the 10-k Ω strap to ground or V_{DD}. As with the series termination resistor, the output strapping resistor should be placed as close to the I/O pin as possible in order to keep the interconnecting trace short. The trace from the resistor to ground or V_{DD} should be kept less than two inches in length to minimize system noise coupling during input logic sampling.

When the clock outputs are enabled following the 2-ms input period, the corresponding specified output frequency is delivered on the pins, assuming that V_{DD} has stabilized. If V_{DD} has not yet reached full value, output frequency initially may be below target but will increase to target once V_{DD} voltage has stabilized. In either case, a short output clock cycle may be produced from the CPU clock outputs when the outputs are enabled.



Figure 1. Input Logic Selection Through Resistor Load Option





Figure 2. Input Logic Selection Through Jumper Option

Spread Spectrum Generator

The device generates a clock that is frequency modulated in order to increase the bandwidth that it occupies. By increasing the bandwidth of the fundamental and its harmonics, the amplitudes of the radiated electromagnetic emissions are reduced. This effect is depicted in *Figure 3*.

As shown in *Figure 3*, a harmonic of a modulated clock has a much lower amplitude than that of an unmodulated signal. The reduction in amplitude is dependent on the harmonic number and the frequency deviation or spread. The equation for the reduction is

dB = 6.5 + 9*log10(P) + 9*log10(F)

Where P is the percentage of deviation and F is the frequency in MHz where the reduction is measured.

The output clock is modulated with a waveform depicted in *Figure 4*. This waveform, as discussed in "Spread Spectrum Clock Generation for the Reduction of Radiated Emissions" by Bush, Fessler, and Hardin produces the maximum reduction in the amplitude of radiated electromagnetic emissions. The deviation selected for this chip is specified in *Table 6. Figure 4* details the Cypress spreading pattern. Cypress does offer options with more spread and greater EMI reduction. Contact your local Sales representative for details on these devices.

Spread Spectrum clocking is activated or deactivated by selecting the appropriate values for bits 1–0 in data byte 0 of the SMBus data stream. Refer to *Table 7* for more details.



Figure 3. Clock Harmonic with and without SSCG Modulation Frequency Domain Representation





Figure 4. Typical Modulation Profile

Serial Data Interface

The CYW150 features a two-pin, serial data interface that can be used to configure internal register settings that control particular device functions. Upon power-up, the CYW150 initializes with default register settings, therefore the use of this serial data interface is optional. The serial interface is write-only (to the clock chip) and is the dedicated function of device pins SDATA and SCLOCK. In motherboard applications, SDATA and SCLOCK are typically driven by two logic

outputs of the chipset. If needed, clock device register changes are normally made upon system initialization. The interface can also be used during system operation for power management functions. Table 3 summarizes the control functions of the serial data interface.

Operation

Data is written to the CYW150 in eleven bytes of eight bits each. Bytes are written in the order shown in Table 4.

Control Function	Description	Common Application
	Disabled outputs are actively held LOW.	Unused outputs are disabled to reduce system power. Examples are clock our unused PCI slots.

Table 3.	Serial E	Data Interface	Control	Functions	Summary
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Clock Output Disable	Any individual clock output(s) can be disabled. Disabled outputs are actively held LOW.	Unused outputs are disabled to reduce EMI and system power. Examples are clock outputs to unused PCI slots.
CPU Clock Frequency Selection	Provides CPU/PCI frequency selections through software. Frequency is changed in a smooth and controlled fashion.	For alternate microprocessors and power management options. Smooth frequency transition allows CPU frequency change under normal system operation.
Spread Spectrum Enabling	Enables or disables spread spectrum clocking.	For EMI reduction.
Output Three-state	Puts clock output into a high-impedance state.	Production PCB testing.
Test Mode	All clock outputs toggle in relation to X1 input, internal PLL is bypassed. Refer to <i>Table 5</i> .	Production PCB testing.
(Reserved)	Reserved function for future device revision or production device testing.	No user application. Register bit must be written as 0.

Table 4. Byte Writing Sequence

Byte Sequence	Byte Name	Bit Sequence	Byte Description
1	Slave Address	11010010	Commands the CYW150 to accept the bits in Data Bytes 0–7 for internal register configuration. Since other devices may exist on the same common serial data bus, it is necessary to have a specific slave address for each potential receiver. The slave receiver address for the CYW150 is 11010010. Register setting will not be made if the Slave Address is not correct (or is for an alternate slave receiver).
2	Command Code	Don't Care	Unused by the CYW150, therefore bit values are ignored ("Don't Care"). This byte must be included in the data write sequence to maintain proper byte allocation. The Command Code Byte is part of the standard serial communication protocol and may be used when writing to another addressed slave receiver on the serial data bus.
3	Byte Count	Don't Care	Unused by the CYW150, therefore bit values are ignored ("Don't Care"). This byte must be included in the data write sequence to maintain proper byte allocation. The Byte Count Byte is part of the standard serial communication protocol and may be used when writing to another addressed slave receiver on the serial data bus.



Table 4. Byte Writing Sequence (continued)

Byte Sequence	Byte Name	Bit Sequence	Byte Description				
4	Data Byte 0	Refer to Table 5	The data bits in Data Bytes 0-5 set internal CYW150 registers that control device				
5	Data Byte 1		operation. The data bits are only accepted when the Address Byte bit sequence is 11010010, as noted above. For description of bit control functions, refer to <i>Table 5</i> ,				
6	Data Byte 2		Data Byte Serial Configuration Map.				
7	Data Byte 3						
8	Data Byte 4						
9	Data Byte 5						
10	Data Byte 6	Don't Care	Unused by the CYW150, therefore bit values are ignored (Don't Care).				
11	Data Byte 7]					

Writing Data Bytes

Each bit in Data Bytes 0-7 control a particular device function except for the "reserved" bits which must be written as a logic 0. Bits are written MSB (most significant bit) first, which is bit 7.

Table 5 gives the bit formats for registers located in Data Bytes 0–7.

Table 6 details additional frequency selections that are available through the serial data interface.

Table 7 details the select functions for Byte 0, bits 1 and 0.

	Affected Pin		Affected Pin		ontrol	
Bit(s)	Pin No.	Pin Name	Control Function	0	1	Default
Data B	yte 0		•		•	L
7	_	_	(Reserved)	_	_	0
6	_	_	SEL_2	See 7	Table 6	0
5	-	-	SEL_1	See 7	Table 6	0
4	-	_	SEL_0	See 7	Table 6	0
3	_	_	Frequency Table Selection	Frequency Controlled by FS (3:0) <i>Table 2</i>	Frequency Controlled by SEL (3:0) <i>Table 6</i>	0
2	-	_	SEL3	Refer to	Table 6	0
1–0	_	_	Bit 1Bit 0Function (See Table 7 for function details)00Normal Operation01(Reserved)10Spread Spectrum On11All Outputs Three-stated			
Data B	yte 1		•			
7	-	_	-	-	-	0
6	-	_	-	_	-	0
5	-	_	-	-	-	0
4	_	-	-	-	-	0
3	46	SDRAM_F	Clock Output Disable	Low	Active	1
2	49	CPU2	Clock Output Disable	Low	Active	1
1	51	CPU1	Clock Output Disable	Low	Active	1
0	52	CPU_F	Clock Output Disable Low Active			1
Data B	yte 2		-	·		
7	-	-	(Reserved)	-	-	0
6	8	PCI_F	Clock Output Disable	Low	Active	1
5	16	PCI5	Clock Output Disable	Low	Active	1

Table 5. Data Bytes 0–5 Serial Configuration Map



Table 5. Data Bytes 0–5 Serial Configuration Map (continued)

	Affected Pin			Bit C	ontrol	
Bit(s)	Pin No.	Pin Name	Control Function	0	1	Default
4	14	PCI4	Clock Output Disable	Low	Active	1
3	13	PCI3	Clock Output Disable	Low	Active	1
2	12	PCI2	Clock Output Disable	Low	Active	1
1	11	PCI1	Clock Output Disable	Low	Active	1
0	9	PCI0	Clock Output Disable	Low	Active	1
Data B	yte 3					
7	-	_	(Reserved)	-	_	0
6	_	_	(Reserved)	_	_	0
5	29	48MHz	Clock Output Disable	Low	Active	1
4	30	24MHz	Clock Output Disable	Low	Active	1
3	33, 32, 25, 24	SDRAM12:15	Clock Output Disable	Low	Active	1
2	22, 21, 19, 18	SDRAM8:11	Clock Output Disable	Low	Active	1
1	39, 38, 36, 35	SDRAM4:7	Clock Output Disable	Low	Active	1
0	44, 43, 41, 40	SDRAM0:3	Clock Output Disable	Low	Active	1
Data B	yte 4	I			I	
7	_	_	(Reserved)	-	_	0
6	_	_	(Reserved)	_	_	0
5	-	_	(Reserved)	-	-	0
4	-	-	(Reserved)	-	-	0
3	-	-	(Reserved)	-	-	0
2	-	-	(Reserved)	-	-	0
1	-	-	(Reserved)	-	-	0
0	-	-	(Reserved)	-	-	0
Data B	yte 5					
7	-	-	(Reserved)	-	-	0
6	_	_	(Reserved)	_	_	0
5	54	IOAPIC_F	Disabled	Low	Active	1
4	55	IOAPICO	Disabled	Low	Active	1
3	-	-	(Reserved)	-	-	0
2	-	-	(Reserved)	-	-	0
1	2	REF1	Clock Output Disable	Low	Active	1
0	3	REF0	Clock Output Disable	Low	Active	1



Table 6. Frequency Selections through Serial Data Interface Data Bytes

	Input C	onditions		Output F	requency	Spread On
	Data Byte	e 0, Bit 3 = 1				
Bit 2 SEL_3	Bit 6 SEL_2	Bit 5 SEL_1	Bit 4 SEL_0	CPU, SDRAM Clocks (MHz)	PCI Clocks (MHz)	Spread Percentage
1	1	1	1	133.3	33.3 (CPU/4)	± 0.5% Center
1	1	1	0	124	31 (CPU/4)	± 0.5% Center
1	1	0	1	150	37.5 (CPU/4)	± 0.5% Center
1	1	0	0	140	35 (CPU/4)	± 0.5% Center
1	0	1	1	105	35 (CPU/3)	± 0.5% Center
1	0	1	0	110	36.7 (CPU/3)	± 0.9% Center
1	0	0	1	115	38.3 (CPU/3)	± 0.5% Center
1	0	0	0	120	40 (CPU/3)	± 0.5% Center
0	1	1	1	100	33.3 (CPU/3)	± 0.5% Center
0	1	1	0	133.3	44.43 (CPU/3)	± 0.5% Center
0	1	0	1	112	37.3 (CPU/3)	± 0.5% Center
0	1	0	0	103	34.3 (CPU/3)	± 0.5% Center
0	0	1	1	66.8	33.4 (CPU/2)	± 0.5% Center
0	0	1	0	83.3	41.7 (CPU/2)	± 0.9% Center
0	0	0	1	75	37.5 (CPU/2)	± 0.5% Center
0	0	0	0	124	41.3 (CPU/3)	± 0.5% Center

Table 7. Select Function for Data Byte 0, Bits 0:1

	Input Co	onditions		Ou	tput Condition	S	
	Data Byte 0				REF0:1, IO-		
Function	Bit 1	Bit 0	CPU_F, 1:2	PCI_F, PCI0:5	APIC0,_F	48 MHZ	24 MHZ
Normal Operation	0	0	Note 2	Note 2	14.318 MHz	48 MHz	24 MHz
Test Mode	0	1	X1/2	CPU/(2 or 3)	X1	X1/2	X1/4
Spread Spectrum	1	0	Note 2	Note 2	14.318 MHz	48 MHz	24 MHz
Tristate	1	1	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z

Note:

2. CPU and PCI frequency selections are listed in Table 2 and Table 6.



Absolute Maximum Ratings^[3]

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V _{DD} , V _{IN}	Voltage on any pin with respect to GND	-0.5 to +7.0	V
T _{STG}	Storage Temperature	-65 to +150	°C
Т _В	Ambient Temperature under Bias	-55 to +125	°C
T _A	Operating Temperature	0 to +70	°C
ESD _{PROT}	Input ESD Protection	2 (min)	kV

DC Electrical Characteristics ($T_A = 0^{\circ}C$ to +70°C; $V_{DDQ3} = 3.3V \pm 5\%$; $V_{DDQ2} = 2.5V \pm 5\%$)

Parameter	Desc	ription	Test Condition	Min.	Тур.	Max.	Unit
Supply Cur	rent			11			
I _{DD}	3.3V Supply Current		CPU_F, 1:2= 100 MHz Outputs Loaded ^[4]		320		mA
I _{DD}	2.5V Supply Current		CPU_F, 1:2= 100 MHz Outputs Loaded ^[4]		40		mA
Logic Input	ts			1			
V _{IL}	Input Low Voltage			GND – 0.3		0.8	V
V _{IH}	Input High Voltage			2.0		V _{DD} + 0.3	V
IIL	Input Low Current ^[5]					-25	μΑ
I _{IH}	Input High Current ^[5]					10	μΑ
I _{IL}	Input Low Current (SE	EL100/66#)				-5	μA
I _{IH}	Input High Current (S	EL100/66#)				+5	μA
Clock Outp	outs			1			
V _{OL}	Output Low Voltage		I _{OL} = 1 mA			50	mV
V _{OH}	Output High Voltage		I _{OH} = 1 mA	3.1			V
V _{OH}	Output High Voltage	CPU_F, 1:2, IOAPIC	I _{OH} = -1 mA	2.2			V
I _{OL}	Output Low Current	CPU_F, 1:2	V _{OL} = 1.25V	60	73	85	mA
		PCI_F, PCI1:5	V _{OL} = 1.5V	96	110	130	mA
		IOAPIC0, IOAPIC_F	V _{OL} = 1.25V	72	92	110	mA
		REF0:1	V _{OL} = 1.5V	61	71	80	mA
		48-MHz	V _{OL} = 1.5V	60	70	80	mA
		24-MHz	V _{OL} = 1.5V	60	70	80	mA
		SDRAM0:15, _F	V _{OL} = 1.5V	95	110	130	
I _{OH}	Output High Current	CPU_F, 1:2	V _{OH} = 1.25V	43	60	80	mA
		PCI_F, PCI1:5	V _{OH} = 1.5V	76	96	120	mA
		IOAPIC	V _{OH} = 1.25V	60	90	130	mA
		REF0:1	V _{OH} = 1.5V	50	60	72	mA
		48-MHz	V _{OH} = 1.5V	50	60	72	mA
		24-MHz	V _{OH} = 1.5V	50	60	72	mA
		SDRAM0:15, _F	V _{OH} = 1.5V	75	95	120	

Notes:

3. Multiple Supplies: The voltage on any input or I/O pin cannot exceed the power pin during power-up. Power supply sequencing is NOT required.

4. All clock outputs loaded with 6" 60Ω traces with 22-pF capacitors.

5. CYW150 logic inputs have internal pull-up devices (not to full CMOS level). Logic input FS3 has an internal pull-down device.



DC Electrical Characteristics ($T_A = 0^{\circ}C$ to +70°C; $V_{DDQ3} = 3.3V \pm 5\%$; $V_{DDQ2} = 2.5V \pm 5\%$) (continued)

Parameter	Description	Test Condition	Min.	Тур.	Max.	Unit
Crystal Os	cillator					
V _{TH}	X1 Input threshold Voltage ^[6]	V _{DDQ3} = 3.3V		1.65		V
C _{LOAD}	Load Capacitance, Imposed on External Crystal ^[7]			14		pF
C _{IN,X1}	X1 Input Capacitance ^[8]	Pin X2 unconnected		28		pF
Pin Capaci	tance/Inductance		•			
C _{IN}	Input Pin Capacitance	Except X1 and X2			5	pF
C _{OUT}	Output Pin Capacitance				6	pF
L _{IN}	Input Pin Inductance				7	nH

AC Electrical Characteristics

 $T_A = 0^{\circ}C$ to +70°C; $V_{DDQ3} = 3.3V\pm5\%$; $V_{DDQ2} = 2.5V\pm5\%$; $f_{XTL} = 14.31818$ MHz. AC clock parameters are tested and guaranteed over stated operating conditions using the stated lump capacitive load at the clock output; Spread Spectrum clocking is disabled.

CPU Clock Outputs, CPU_F, 1:2 (Lump Capacitance Test Load = 20 pF)

			CPU	= 66.8	8 MHz	CPU = 100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t _P	Period	Measured on rising edge at 1.25	15		15.5	10		10.5	ns
t _H	High Time	Duration of clock cycle above 2.0V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5.0			2.8			ns
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.0V	1		4	1		4	V/ns
t _F	Output Fall Edge Rate	Measured from 2.0V to 0.4V	1		4	1		4	V/ns
t _D	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	45		55	%
t _{JC}	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Maximum difference of cycle time between two adjacent cycles.			250			250	ps
t _{SK}	Output Skew	Measured on rising edge at 1.25V			175			175	ps
f _{ST}	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3			3	ms
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		20			20		Ω

PCI Clock Outputs, PCI_F and PCI0:5 (Lump Capacitance Test Load = 30 pF)

			CPU = 66.6/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
t _P	Period	Measured on rising edge at 1.5V	30			ns
t _H	High Time	Duration of clock cycle above 2.4V	12.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	12.0			ns
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	1		4	V/ns

Notes:

X1 input threshold voltage (typical) is V_{DDQ3}/2.
 The CYW150 contains an internal crystal load capacitor between pin X1 and ground and another between pin X2 and ground. Total load placed on crystal is 14 pF; this includes typical stray capacitance of short PCB traces to crystal.
 X1 input capacitance is applicable when driving X1 with an external clock source (X2 is left unconnected).

t _F Output Fall Edge Rate Measured from 2.4V to 0.4V 1 4 V/ns	t _F	Output Fall Edge Rate		1		4	
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PCI Clock Outputs, PCI_F and PCI0:5 (Lump Capacitance Test Load = 30 pF) (continued)

			CPU	= 66.6/100) MHz	
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
t _D	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
t _{JC}	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.5V. Maximum difference of cycle time between two adjacent cycles.			250	ps
t _{SK}	Output Skew	Measured on rising edge at 1.5V			500	ps
t _O	CPU to PCI Clock Skew	Covers all CPU/PCI outputs. Measured on rising edge at 1.5V. CPU leads PCI output.	1.5		4	ns
f _{ST}	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		15		Ω

IOAPIC0 and IOAPIC_F Clock Outputs (Lump Capacitance Test Load = 20 pF)

			CPU = 66.6/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Frequency generated by crystal oscillator		14.31818		MHz
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.0V	1		4	V/ns
t _F	Output Fall Edge Rate	Measured from 2.0V to 0.4V	1		4	V/ns
t _D	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	%
f _{ST}	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			1.5	ms
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		15		Ω

REF0:1 Clock Outputs (Lump Capacitance Test Load = 20 pF)

			CPU = 66.6/100 MH			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Frequency generated by crystal oscillator		14.318		MHz
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	0.5		2	V/ns
t _F	Output Fall Edge Rate	Measured from 2.4V to 0.4V	0.5		2	V/ns
t _D	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f _{ST}	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		25		Ω

SDRAM 0:15, _F Clock Outputs (Lump Capacitance Test Load = 30 pF)

			CPU = 66.8 MHz		MHz	CPU	MHz		
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t P	Period	Measured on rising edge at 1.5V	15		15.5	10		10.5	ns
t _H	High Time	Duration of clock cycle above 2.4V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5.0			2.0			ns
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	1		4	1		4	V/ns
t _F	Output Fall Edge Rate	Measured from 2.4V to 0.4V	1		4	1		4	V/ns



SDRAM 0:15, _F Clock Outputs (Lump Capacitance Test Load = 30 pF) (continued)

			CPU = 66.8 MHz CPU		J = 100 MHz				
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t _D	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	45		55	%
t _{SK}	Output Skew	Measured on rising and falling edge at 1.5V			250			250	ps
t _{PD}	Propagation Delay	Measured from SDRAMIN		3.7			3.7		ns
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		15			15		Ω

48-MHz Clock Output (Lump Capacitance Test Load = 20 pF)

				CPU = 66.8/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit	
f	Frequency, Actual	Determined by PLL divider ratio (see m/n below)	48.008		MHz		
f _D	Deviation from 48 MHz	(48.008 - 48)/48	+167			ppm	
m/n	PLL Ratio	(14.31818 MHz x 57/17 = 48.008 MHz)	57/17				
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	0.5		2	V/ns	
t _F	Output Fall Edge Rate	Measured from 2.4V to 0.4V	0.5		2	V/ns	
t _D	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%	
f _{ST}	Frequency Stabilization from Power-up (cold start)	n Power-up (cold power-up. Short cycles exist prior to frequency stabili-			3	ms	
Z _o	AC Output Impedance	Average value during switching transition. Used for deter- mining series termination value.		25		Ω	

24-MHz Clock Output (Lump Capacitance Test Load = 20 pF

			CPU = 66.8/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Determined by PLL divider ratio (see m/n below)	24.004			MHz
f _D	Deviation from 24 MHz	(24.004 - 24)/24	+167			ppm
m/n	PLL Ratio	(14.31818 MHz x 57/34 = 24.004 MHz)	57/34			
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	0.5		2	V/ns
t _F	Output Fall Edge Rate	Measured from 2.4V to 0.4V	0.5		2	V/ns
t _D	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f _{ST}	Frequency Stabilization from Power-up (cold start)	Power-up (cold power-up. Short cycles exist prior to frequency stabili-			3	ms
Z _o	AC Output Impedance	Average value during switching transition. Used for determining series termination value.25		25		Ω

Layout Example



CYW150



FB = Dale ILB1206 - 300 (300 Ω @ 100 MHz) Cermaic Caps C1 & C3 = 10 – 22 $\,\mu F$ C2 & C4 = 0.005 μF

 (\mathbf{G}) = VIA to GND plane layer (\mathbf{V}) =VIA to respective supply plane layer

Note: Each supply plane or strip should have a ferrite bead and capacitors All bypass caps = 0.1 μF ceramic



Ordering Information

Ordering Code	Package Type	Industrial Product Flow
CYW150OXC	56-pin SSOP	Commercial, 0 to 70°C
CYW150OXCT	56-pin SSOP – Tape and Reel	Commercial, 0 to 70°C

Package Drawing and Dimensions



56-Lead Shrunk Small Outline Package O56

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